Product data sheet

1. General description

Planar passivated SCR with sensitive gate in a SOT223 surface mountable plastic package. This SCR is designed to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

2. Features and benefits

- Sensitive gate
- Planar passivated for voltage ruggedness and reliability
- Direct triggering from low power drivers and logic ICs
- Surface mountable package

3. Applications

- Ground Fault Circuit Interrupters (GFCI)
- · General purpose switching and phase control
- · Ignition circuits, CDI for 2- and 3-wheelers
- Motor control e.g. small kitchen appliances

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{DRM}	repetitive peak off- state voltage			-	-	1000	V
V_{RRM}	repetitive peak reverse voltage			-	-	1000	V
I _{T(AV)}	average on-state current	half sine wave; $T_{sp} \le 100 ^{\circ}\text{C}$		-	-	0.8	Α
I _{T(RMS)}	RMS on-state current	half sine wave; $T_{sp} \le 100 ^{\circ}\text{C}$; Fig. 1; Fig. 2; Fig. 3		-	-	1.1	Α
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; t_p = 10 ms; Fig. 4; Fig. 5		-	-	11	Α
Static characteristics							
I _{GT}	gate trigger current	$V_D = 12 \text{ V}; I_T = 10 \text{ mA}; T_j = 25 \text{ °C};$ Fig. 7		1	-	100	μΑ

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode	4	А - К
2	Α	anode		G sym037
3	G	gate		Symosi
4	Α	mb; connected to anode	☐1 ☐2 ☐3 SC-73 (SOT223)	

6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
NCR100W-12M	SC-73	plastic surface-mounted package with increased heatsink; 4 leads	SOT223		

7. Marking

Table 4. Marking codes

Type number	Marking code
NCR100W-12M	10012M

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DRM}	repetitive peak off-state voltage		-	1000	V
V_{RRM}	repetitive peak reverse voltage		-	1000	V
I _{T(AV)}	average on-state current	half sine wave; T _{sp} ≤ 100 °C	-	0.8	Α
I _{T(RMS)}	RMS on-state current	half sine wave; $T_{sp} \le 100 ^{\circ}\text{C}$; Fig. 1; Fig. 2; Fig. 3	-	1.1	А
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 10 \text{ ms}$; Fig. 4; Fig. 5	-	11	А
		half sine wave; T _{j(init)} = 25 °C; t _p = 8.3 ms	-	12.1	Α
I ² t	I ² t for fusing	t _p = 10 ms; SIN	-	0.605	A²s
dl _T /dt	rate of rise of on-state current	I _G = 0.1 mA	-	50	A/µs
I _{GM}	peak gate current		-	1	Α
V_{RGM}	peak reverse gate voltage		-	5	V
P_{GM}	peak gate power		-	2	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.1	W
T _{stg}	storage temperature		-40	150	°C
T _j	junction temperature		-	125	°C

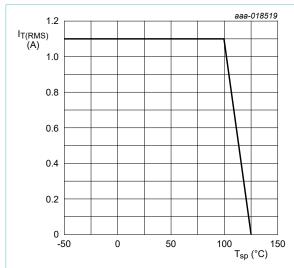


Fig. 1. RMS on-state current as a function of solder point temperature; maximum values

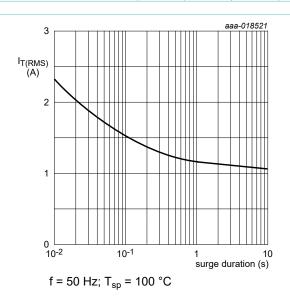


Fig. 2. RMS on-state current as a function of surge duration; maximum values

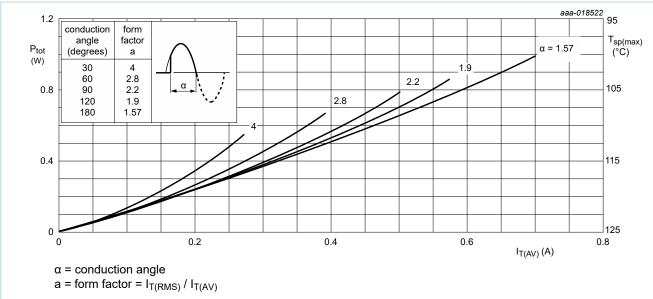


Fig. 3. Total power dissipation as a function of average on-state current; maximum values

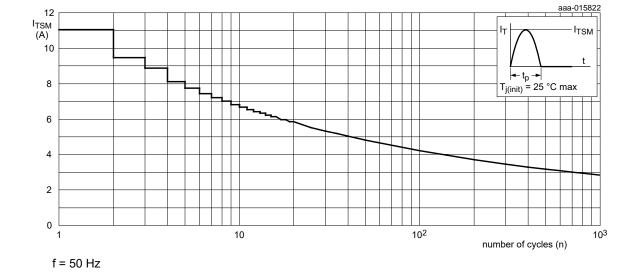
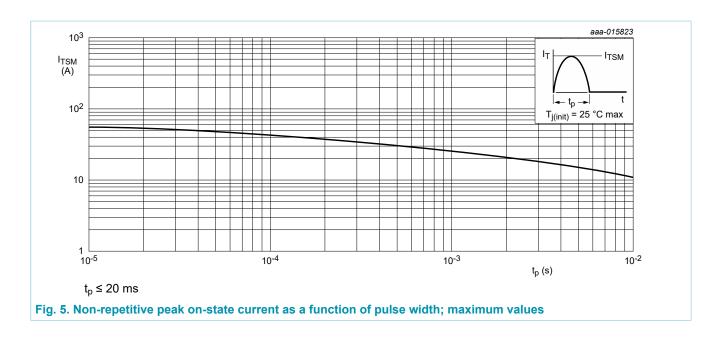


Fig. 4. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values

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9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-sp)}$	thermal resistance from junction to solder point	half cycle; Fig. 6	-	-	25	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	printed circuit board mounted; minimum footprint; in free air	-	130	-	K/W

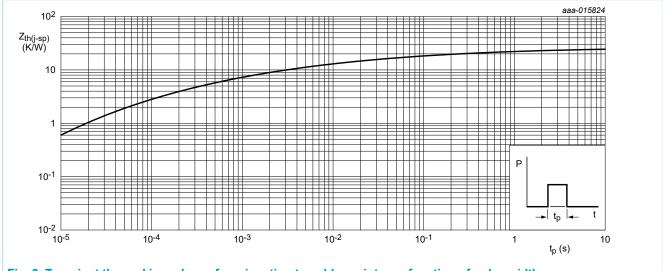


Fig. 6. Transient thermal impedance from junction to solder point as a function of pulse width

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10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static char	acteristics					
I _{GT}	gate trigger current	$V_D = 12 \text{ V; } I_T = 10 \text{ mA; } T_j = 25 \text{ °C;}$ Fig. 7		-	100	μA
IL	latching current	$V_D = 12 \text{ V; } I_G = 0.5 \text{ mA; } T_j = 25 \text{ °C;}$ $R_{GK(ext)} = 1 \text{ k}\Omega; \frac{\text{Fig. 8}}{\text{Fig. 8}}$		-	6	mA
I _H	holding current	V_D = 12 V; T_j = 25 °C; $R_{GK(ext)}$ = 1 kΩ; Fig. 9	-	-	3	mA
V_{T}	on-state voltage	I _T = 1.2 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.25	1.7	V
V _{GT} gate	gate trigger voltage	$V_D = 12 \text{ V}; I_T = 10 \text{ mA}; T_j = 25 \text{ °C};$ Fig. 11	-	0.5	0.8	V
		$V_D = 1000 \text{ V}; I_T = 0.1 \text{ A}; T_j = 125 \text{ °C};$ Fig. 11	0.3	0.5	-	V
I _D	off-state current	$V_D = 1000 \text{ V}; R_{GK(ext)} = 1 \text{ k}\Omega;$ $T_j = 125 \text{ °C}$	-	0.05	1	mA
I _R	reverse current	V_R = 1000 V; T_j = 125 °C; $R_{GK(ext)}$ = 1 k Ω	-	0.05	1	mA
Dynamic cl	naracteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 670 V; T_j = 125 °C; R_{GK} = 1 k Ω ; exponential waveform; (V_{DM} = 67% of V_{DRM})	100	-	-	V/µs
t _{gt}	gate-controlled turn-on time	I_{TM} = 2 A; V_D = 1000 V; I_G = 10 mA; dI_G/dt = 0.1 A/ μ s; T_j = 25 °C	-	2	-	μs
t _q	commutated turn-off time	V_{DM} = 670 V; T_j = 125 °C; I_{TM} = 1.6 A; V_R = 35 V; $(dI_T/dt)_M$ = 30 A/ μ s; dV_D/dt = 2 V/ μ s; $R_{GK(ext)}$ = 1 k Ω ; $(V_{DM}$ = 67% of $V_{DRM})$	-	100	-	μs

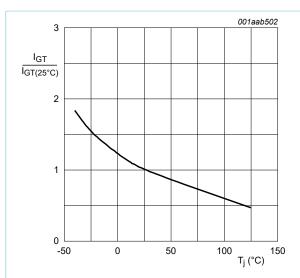


Fig. 7. Normalized gate trigger current as a function of junction temperature

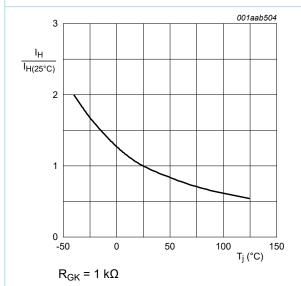


Fig. 9. Normalized holding current as a function of junction temperature

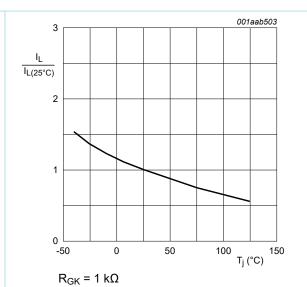
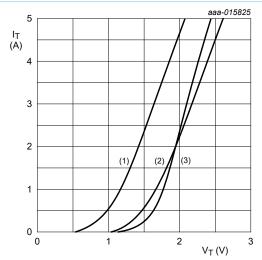


Fig. 8. Normalized latching current as a function of junction temperature



 V_o = 1.289 V; R_s = 0.292 Ω

(1) $T_j = 125$ °C; typical values (2) $T_j = 125$ °C; maximum values

(3) T_j = 25 °C; maximum values

Fig. 10. On-state current as a function of on-state voltage

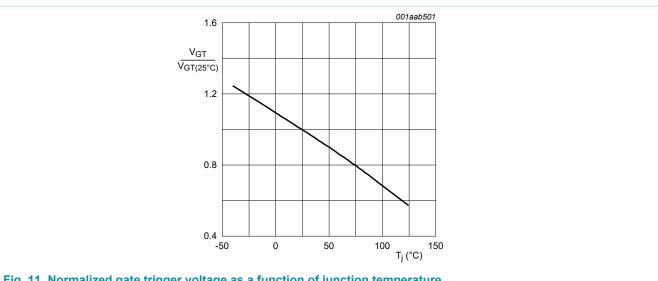


Fig. 11. Normalized gate trigger voltage as a function of junction temperature

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11. Package outline

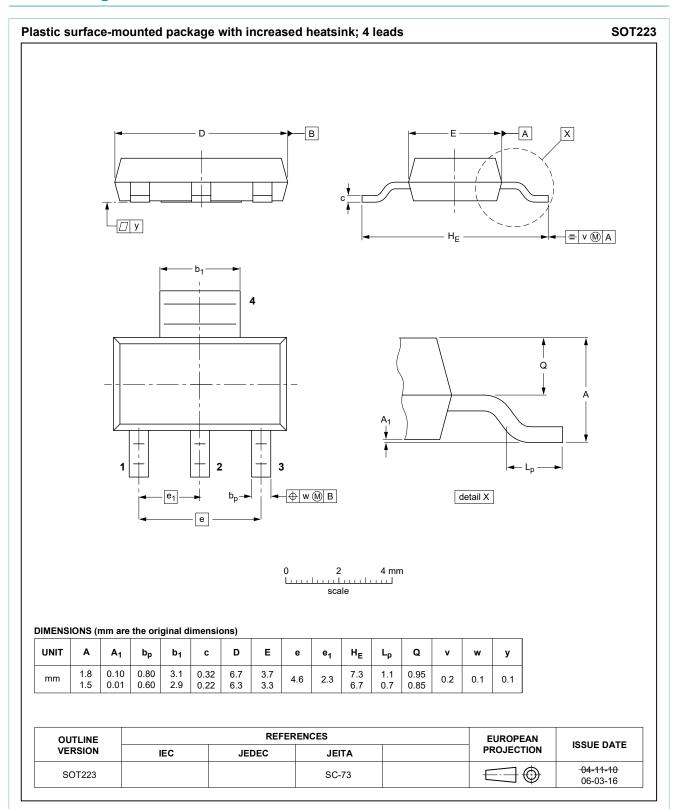
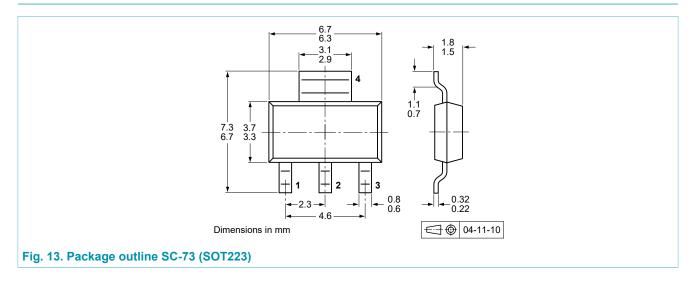
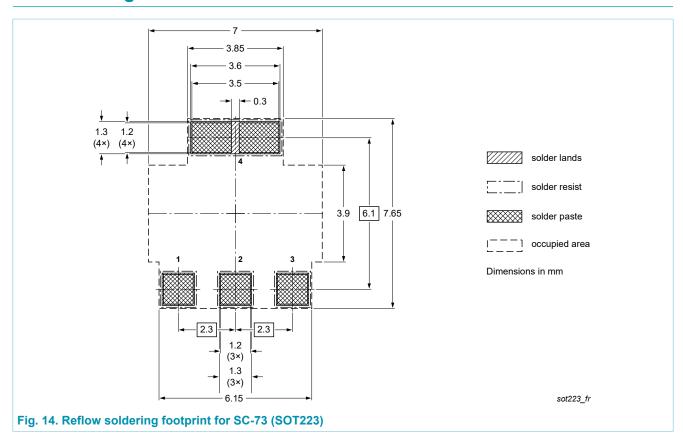


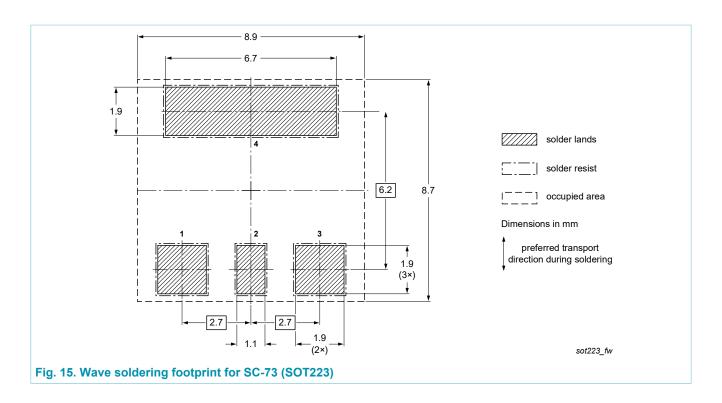
Fig. 12. Package outline SC-73 (SOT223)

12. Package outline (minimized)



13. Soldering





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14. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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